d-Electrons in Crystalline and Amorphous V₂O₅ and MoO₃ Compounds*

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The characteristic features of electron spin resonance (ESR) spectra of nonstoichiometric V_2O_5 and MoO_3 are surveyed.

In their stoichiometric form V_2O_5 and MoO_3 should be diamagnetic insulators. The 3*d* and 4*d* orbitals are not occupied (d^0 configuration). Various possibilities, however, are known to produce nonstoichiometric compounds of V_2O_5 and MoO_3 which contain a nonintegral number of *d* electrons per transition element lattice site: formation of transition element bronzes (*I*), substitution of transition element ions, oxygen deficiency, and adding of glassformers, etc.

The behavior of these additional d electrons is essentially determined by electron-phonon interaction which favors polaron formation, by interaction with nonperiodic Coulomb fields which may lead to Anderson localization, by electron correlation energy, etc. (2).

Electron spin resonance (EPR) is a powerful tool used to investigate localized d states and thus to gain information on the electronic structure of these compounds.

Because of spin S = 1/2 we expect one electronic transition in the ESR spectra of d electrons on nonstoichiometric V₂O₅ and MoO₃ compounds. The g-tensor, which is derived from the resonance fields, yields information on the ground state and the crystal field splitting. From the hyperfine interaction of the d electrons with vanadium (I = 7/2) or molybdenum nuclei (I = 5/2) we may deduce the extent of localization or delocalization of the d states. From linewidth

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Copyright © 1975 by Academic Press, Inc. All rights of reproduction in any form reserved. Printed in Great Britain studies we learn about relaxation times, mobile behavior, etc.

ESR investigations of different classes of nonstoichiometric V_2O_5 and MoO_3 compounds are known (3, 4). This paper surveys the characteristic features of the ESR signals of some of these compounds, where the measurements were performed over large



FIG. 1. Review of ESR spectra of some nonstoichiometric V_2O_5 and MoO₃ compounds.

V₂O₅ AND MoO₃ COMPOUNDS ESR

TABLE I

Features Typical of the ESR Spectra of some Nonstoichiometric V_2O_5 and MoO_3 Compounds, and their Interpretation

| Compound | Essential features of the ESR spectra | Interpretation |
|--|---|--|
| $Na_{0.01}V_2O_5$ $T\approx 4^{\circ}K$ | Inhomogeneously broadened gaussian line | Na ⁺ in an asymmetric position in respect to the neighbored vanadium sites |
| <i>T</i> ≈ 100°K | Resolved <i>HF</i> -splitting, equal interaction with four vanadium nuclei | Anderson localization of $3d$ electrons on four vanadium sites within the nonperiodic Cou- lomb field of the Na ⁺ ion, distances between Na ⁺ ion and four vanadium sites are equal (symmetric position) |
| $T \approx 300$ | Narrowed lorentzian line | Hopping mechanism of d electrons causes a line narrowing, hopping frequency is larger than hyperfine splitting in frequency units |
| $Cu_xV_2O_5$ 0.26 < x < 0.64 | g shift negative; asymmetry of the structure- less ESR line depends on orientation of the crystal with respect to the <i>E</i> -field of the microwave | Incorporation of copper as Cu ⁺ ion; strong anisotropy in the electrical conductivity; one- dimensional metallic conductivity along mono- clinic <i>b</i> -axis |
| $K_{0.33}MoO_3$ $T \sim 40^{\circ}K$ | Resolved <i>HF</i> -splitting, relatively small line- width, low signal intensity | Most of the 4 <i>d</i> electrons are spin-paired ($S = 0$); deviation of x from the ideal value of $x = 1/3$; delocalization of 4 <i>d</i> electrons over different number of Mo orbitals |
| MoO_3 -Te O_2 V_2O_5 -Te O_2 Amorph. | Resolved <i>HF</i> -splitting, the linewidth increases with resonance frequency | Localization of d electrons on one vanadium or molybdenum site; well defined micro- environment; hopping frequency even at room temperature smaller than hyperfine splitting in frequency units |
| $V_2 MoO_8 = V_2O_5 \cdot MoO_3$ | Extremely narrowed linewidth, orientation dependence typical for narrowing of a large hyperfine splitting | Localization of the d electrons on vanadium $3d$ sites but not in molybdenum $4d$ orbitals; hopping mobility of the d electrons |

temperature regions, and at different resonance frequencies.

Figure 1 shows typical ESR spectra of d electrons in the mentioned compounds. In some cases a HF splitting is resolved, in other compounds a structureless signal occurs, the spectra change with temperature and (in the amorphous compounds) with frequency. The negative g-shift compared with the value of free electrons (g-factors around 1.96) shows in a unique way that the ESR signals are caused by d electrons in a noncubic environment.

Table I summarizes the essential features of

the ESR spectra and the corresponding interpretation.

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